IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Atty. Docket

002372.00043

No.:

Hiroyuki KANAYA et al.

Serial No.:

TBA

Group Art Unit:

TBA

Filed:

June 25, 2003

Examiner:

TBA

For:

Semiconductor Device Having Ferroelectric Capacitor and Hydrogen

Barrier Film and Manufacturing Method Thereof

SUBMISSION OF CORRECTED FORMAL DRAWINGS

Commissioner for Patents P.O. Box 1460 Alexandria, VA 22313-1450

Sir:

Attached are three (3) sheets of <u>corrected</u> formal drawings (Figs. 9, 32, 52 and 53) for filing in the above application. The corrections were previously approved in patent application 09/570,026.

Respectfully submitted,

By:

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Date: <u>June 25, 2003</u>

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